

Features

- Wide supply voltage range from 0.8V to 3.6V
- Inputs accept voltages up to 3.6V
- I_{OFF} supports partial-power-down mode
- Low static power consumption; I_{CC}=0.5μA (Max.)
- ESD Protection Exceeds JESD 22
 - 2000-V Human-Body Model (A114-A)
 - 200-V Machine Model (A115-A)
 - 1000-V Charged-Device Model (C101)

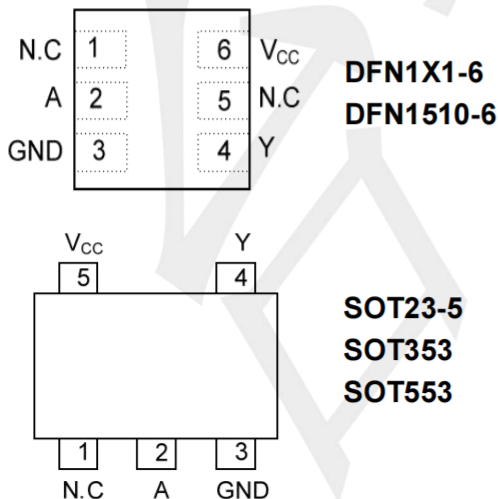
General Description

This SN74AUP1G14 functions as an independent gate with Schmitt-trigger inputs, which allows for slow input transition and better switching-noise immunity at the input. This device ensures a very low static and dynamic power consumption across the entire VCC range from 0.8V to 3.6V.

Ordering Information

ORDER NUMBER	PACKAGE DESCRIPTION	PACKAGE OPTION
SN74AUP1G14DBVR-TP	SOT23-5	Tape and Reel,3000
SN74AUP1G14DCKR-TP	SOT353	Tape and Reel,3000
SN74AUP1G14DRLR-TP	SOT553	Tape and Reel,4000
SN74AUP1G14DSFR-TP	DFN1X1-6	Tape and Reel,5000
SN74AUP1G14DRYR-TP	DFN1510-6	Tape and Reel,5000

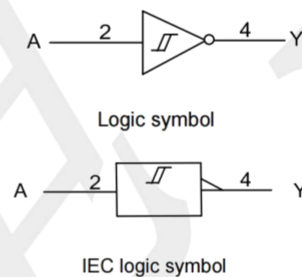
Pin Configuratio (TOP VIEW)



Applications

- AV Receiver
- Audio Dock:Portable
- Blu-ray Player and Home Theater
- Embedded PC
- Personal Digital Assistant(PDA)
- Power:Telecom/Server AC/DC Supply:Single Controller:Analog and Digital
- Solid State Drive(SSD):Client and Enterprise
- Wireless Headset,Keyboard,and Mouse

Logic Diagram



Function Table (each gate)

INPUT (A)	OUTPUT (Y)
L	H
H	L

Note:H: HIGH voltage level;L: LOW voltage level.

Absolute Maximum Ratings

PARAMETER	SYMBOL	CONDITIONS	RATINGS	UNIT
Supply Voltage	V _{CC}		-0.5 ~ +4.6	V
Input Voltage	V _{IN}		-0.5 ~ +4.6	V
Output Voltage	V _{OUT}	Output in the high or low state	-0.5 ~ +V _{CC} +0.5V	V
		Output in the power-off state	-0.5 ~ +4.6	V
VCC or GND Current	I _{CC}		±50	mA
Continuous Output Current	I _{OUT}	V _{OUT} =0~V _{CC}	±20	mA
Input Clamp Current	I _{IK}	V _{IN} <0	-50	mA
Output Clamp Current	I _{OK}	V _{OUT} <0	-50	mA
Storage Temperature Range	T _{STG}		-65 ~ +150	°C
Junction to Ambient	θ _{JA}	SOT-23-5	230	°C/W
		SOT353	280	°C/W
		SOT553	250	°C/W
		DFN1X1-6	460	°C/W
		DFN1510-6	440	°C/W

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

Recommended Operating Conditions

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Supply Voltage	V _{CC}	Operating	0.8	--	3.6	V
Input Voltage	V _{IN}		0	--	3.6	V
Output Voltage	V _{OUT}	High or low state	0	--	V _{CC}	V
Input Transition Rise or Fall Rate	Δt/Δv	V _{CC} =0.8V ~ 3.6V	--	--	200	ns/V
Operating Temperature	T _A		-40	--	+125	°C

Electrical Characteristics (T_A=25°C ,unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Positive-Going Input Threshold Voltage	V _{T+}	V _{CC} = 0.8V	0.3	--	0.6	V
		V _{CC} = 1.1V	0.53	--	0.9	V
		V _{CC} = 1.4V	0.74	--	1.11	V
		V _{CC} = 1.65V	0.91	--	1.29	V
		V _{CC} = 2.3V	1.37	--	1.77	V
		V _{CC} = 3V	1.88	--	2.29	V
Negative-Going Input Threshold Voltage	V _{T-}	V _{CC} = 0.8V	0.1	--	0.6	V
		V _{CC} = 1.1V	0.26	--	0.65	V
		V _{CC} = 1.4V	0.39	--	0.75	V
		V _{CC} = 1.65V	0.47	--	0.84	V
		V _{CC} = 2.3V	0.69	--	1.04	V
		V _{CC} = 3V	0.88	--	1.24	V
Hysteresis Voltage (V _{T+} -V _{T-})	ΔV _T	V _{CC} = 0.8V	0.07	--	0.5	V
		V _{CC} = 1.1V	0.08	--	0.46	V
		V _{CC} = 1.4V	0.18	--	0.56	V
		V _{CC} = 1.65V	0.27	--	0.66	V
		V _{CC} = 2.3V	0.53	--	0.92	V
		V _{CC} = 3V	0.79	--	1.31	V
High-Level Output Voltage	V _{OH}	V _{CC} = 0.8V ~ 3.6V, I _{OH} = -20μA	V _{CC} -0.1	--	--	V
		V _{CC} = 1.1V, I _{OH} = -1.1mA	0.75×V _{CC}	--	--	V
		V _{CC} = 1.4V, I _{OH} = -1.7mA	1.11	--	--	V
		V _{CC} = 1.65V, I _{OH} = -1.9mA	1.32	--	--	V
		V _{CC} = 2.3V	I _{OH} = -2.3mA	2.05	--	V
			I _{OH} = -3.1mA	1.9	--	V
		V _{CC} = 3V	I _{OH} = -2.7mA	2.72	--	V
			I _{OH} = -4mA	2.6	--	V

Electrical Characteristics (T_A=25°C ,unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Low-Level Output Voltage	V _{OL}	V _{CC} =0.8V ~ 3.6V, I _{OL} =20μA		--	--	0.1	V
		V _{CC} =1.1V, I _{OL} =1.1mA		--	--	0.3×V _{CC}	V
		V _{CC} =1.4V, I _{OL} =1.7mA		--	--	0.31	V
		V _{CC} =1.65V, I _{OL} =1.9mA		--	--	0.31	V
		V _{CC} =2.3V	I _{OL} =2.3mA	--	--	0.31	V
			I _{OL} =3.1mA	--	--	0.44	V
		V _{CC} =3V	I _{OL} =2.7mA	--	--	0.31	V
			I _{OL} =4mA	--	--	0.44	V
Input Leakage Current	I _{I(LEAK)}	V _{CC} =0V ~ 3.6V, V _{IN} =V _{CC} or GND		--	--	±0.1	μA
Power OFF Leakage Current	I _{OFF}	V _{CC} =0V, V _{IN} or V _{CC} =3.6V		--	--	±0.2	μA
Additional Power OFF Leakage Current	ΔI _{OFF}	V _{CC} =0V~0.2V, V _{IN} or V _{OUT} =0V~3.6V		--	--	±0.2	μA
Quiescent Supply Current	I _{CC}	V _{CC} =0.8V ~3.6V, I _{OUT} =0 V _{IN} =V _{CC} or GND		--	--	0.5	μA
Additional Quiescent Supply Current	ΔI _{CC}	V _{CC} =3.3V, One input at V _{CC} -0.6V, other inputs at V _{CC} or GND		--	--	40	μA
Input Capacitance	C _I	V _{CC} =0V, V _{IN} =V _{CC} or GND		--	1.5	--	pF
		V _{CC} =3.6V, V _{IN} =V _{CC} or GND		--	1.5	--	pF
Output Capacitance	C _{OUT}	V _{CC} =0V, V _{OUT} =GND		--	2.5	--	pF

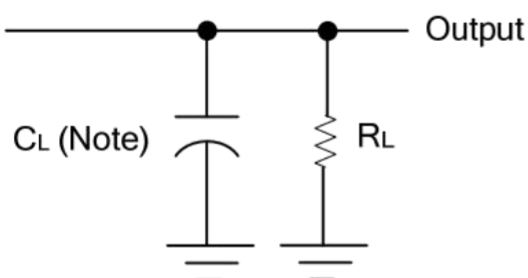
OPERATING CHARACTERISTICS (f=10MHz, TA =25°C , unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power Dissipation Capacitance	C _{PD}	V _{CC} =0.8V	--	4.0	--	pF
		V _{CC} =1.2±0.1V	--	4.0	--	pF
		V _{CC} =1.5±0.1V	--	4.1	--	pF
		V _{CC} =1.8±0.15V	--	4.1	--	pF
		V _{CC} =2.5±0.2V	--	4.3	--	pF
		V _{CC} =3.3±0.3V	--	4.4	--	pF

SWITCHING CHARACTERISTICS (TA =25°C, unless otherwise specified)

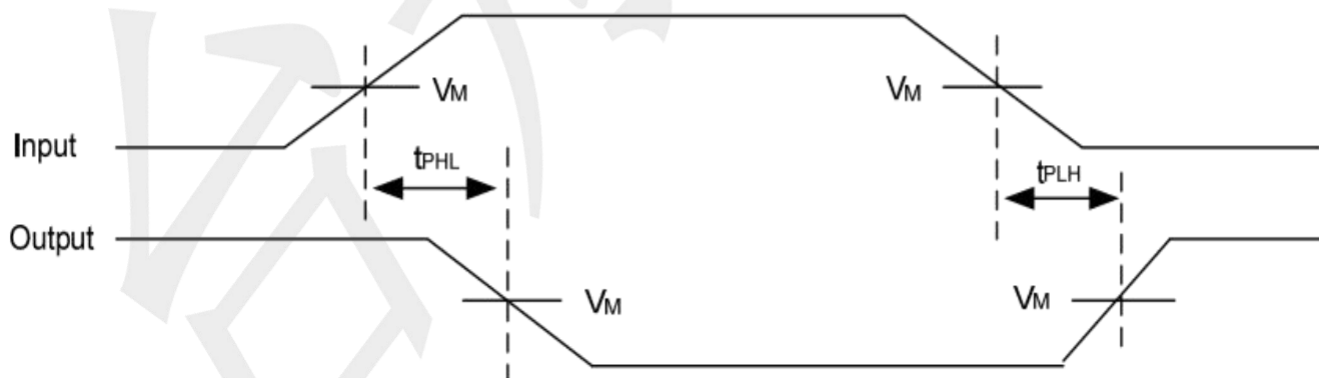
PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Propagation delay from inputs (A) to output(Y)	t _{PD}	CL=5pF, RL=1MΩ	V _{CC} =0.8V	--	20.3	--	ns
			V _{CC} =1.2±0.1V	3.0	6.9	--	ns
			V _{CC} =1.5±0.1V	2.6	5.2	--	ns
			V _{CC} =1.8±0.15V	2.2	4.4	--	ns
			V _{CC} =2.5±0.2V	2.0	3.5	--	ns
			V _{CC} =3.3±0.3V	1.9	3	--	ns
		CL=10pF, RL=1MΩ	V _{CC} =0.8V	--	23.9	--	ns
			V _{CC} =1.2±0.1V	3.5	7.9	--	ns
			V _{CC} =1.5±0.1V	3.0	6	--	ns
			V _{CC} =1.8±0.15V	2.7	5	--	ns
			V _{CC} =2.5±0.2V	2.4	4	--	ns
			V _{CC} =3.3±0.3V	2.4	3.5	--	ns
		CL=15pF, RL=1MΩ	V _{CC} =0.8V	--	27.3	--	ns
			V _{CC} =1.2±0.1V	3.9	8.7	--	ns
			V _{CC} =1.5±0.1V	3.3	6.7	--	ns
			V _{CC} =1.8±0.15V	3.0	5.6	--	ns
			V _{CC} =2.5±0.2V	2.8	4.5	--	ns
			V _{CC} =3.3±0.3V	2.7	3.9	--	ns
		CL=30pF, RL=1MΩ	V _{CC} =0.8V	--	25.7	--	ns
			V _{CC} =1.2±0.1V	5.1	11.2	--	ns
			V _{CC} =1.5±0.1V	4.3	8.5	--	ns
			V _{CC} =1.8±0.15V	3.9	7.2	--	ns
			V _{CC} =2.5±0.2V	3.6	5.7	--	ns
			V _{CC} =3.3±0.3V	3.5	5	--	ns

TEST CIRCUIT AND WAVEFORMS



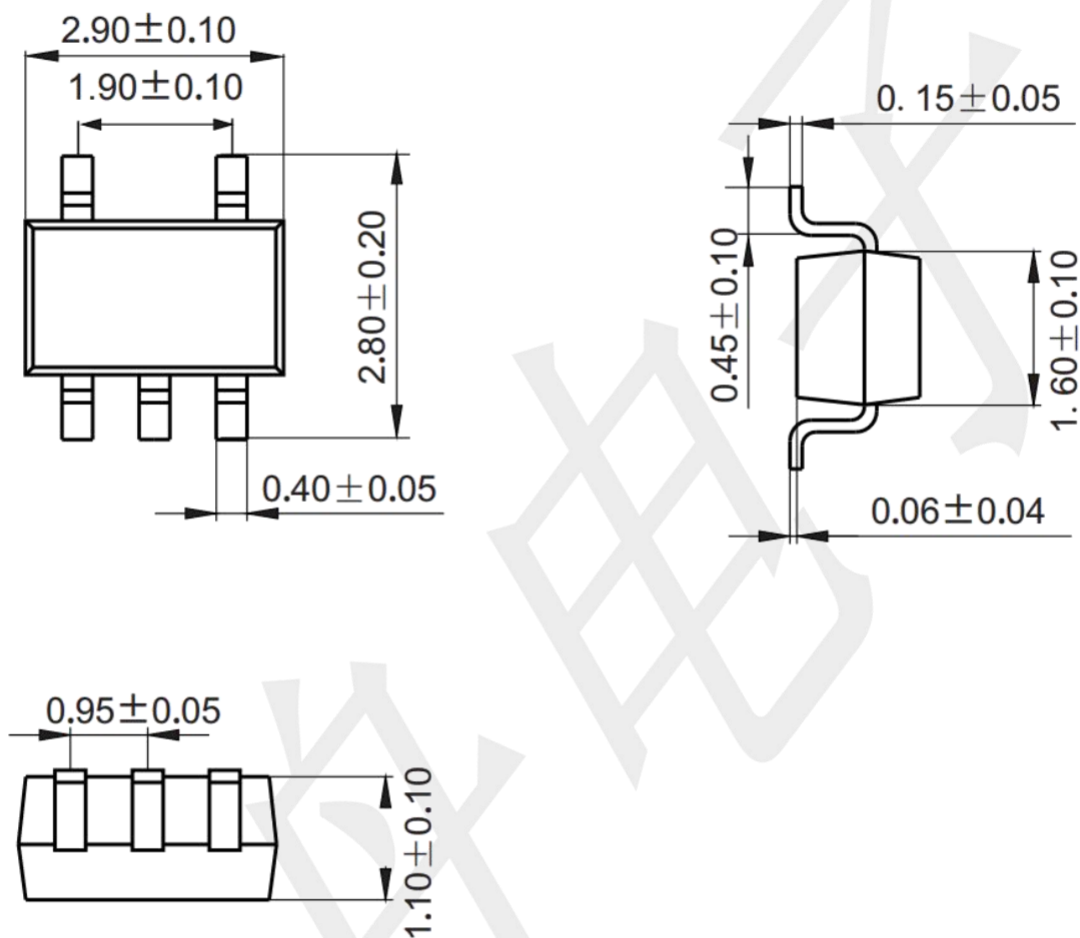
Note: C_L includes probe and jig capacitance.

V_{CC}	V_{IN}	t_R / t_F	V_M	C_L	R_L
0.8V	V_{CC}	$\leq 3ns$	$V_{CC}/2$	5,10,15,30pF	1M Ω
1.2V $\pm$ 0.1V	V_{CC}	$\leq 3ns$	$V_{CC}/2$	5,10,15,30pF	1M Ω
1.5V $\pm$ 0.1V	V_{CC}	$\leq 3ns$	$V_{CC}/2$	5,10,15,30pF	1M Ω
1.8V $\pm$ 0.15V	V_{CC}	$\leq 3ns$	$V_{CC}/2$	5,10,15,30pF	1M Ω
2.5V $\pm$ 0.2V	V_{CC}	$\leq 3ns$	$V_{CC}/2$	5,10,15,30pF	1M Ω
3.3V $\pm$ 0.3V	V_{CC}	$\leq 3ns$	$V_{CC}/2$	5,10,15,30pF	1M Ω

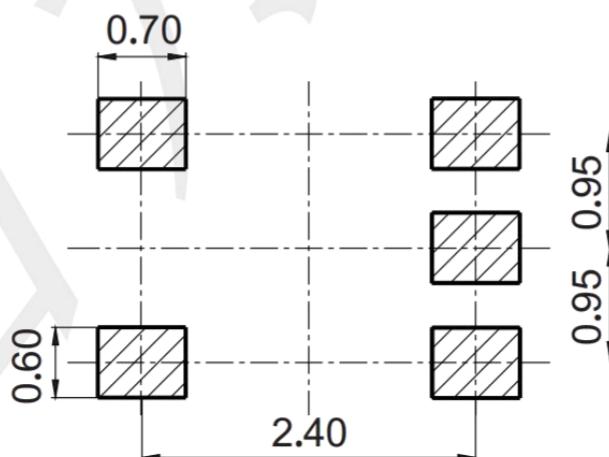


Package information (Unit: mm)

SOT23-5

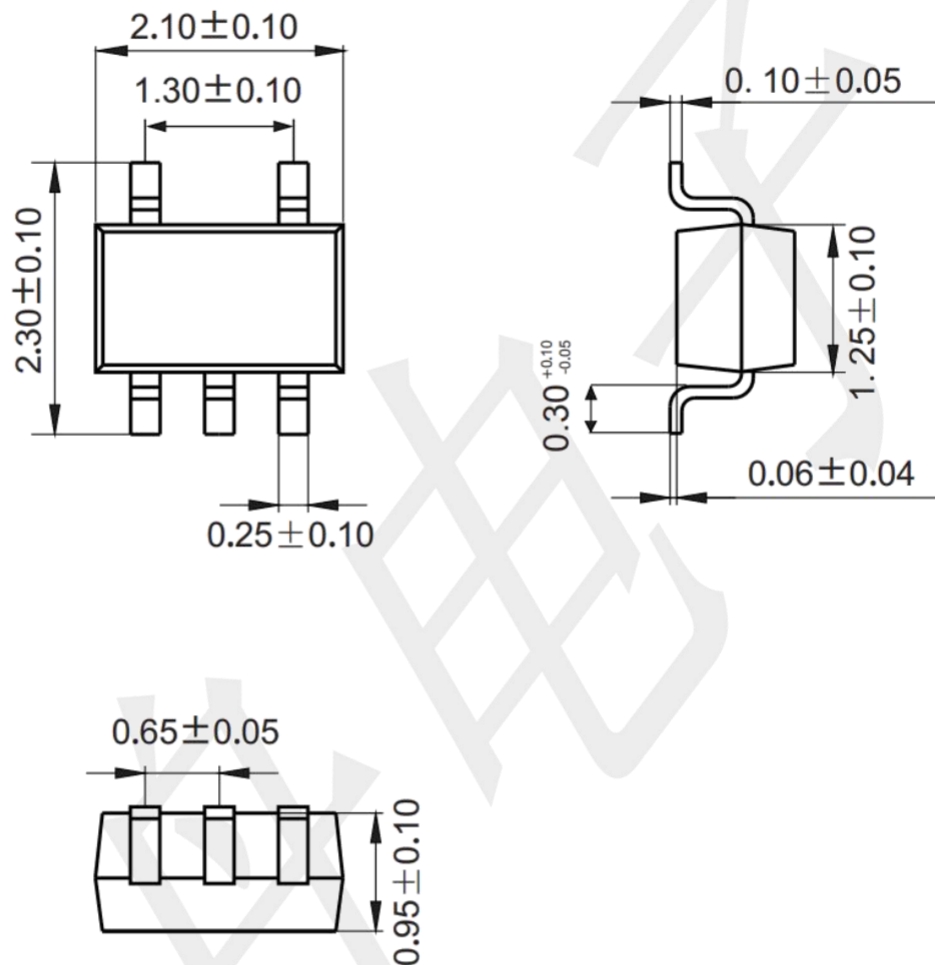


Mounting Pad Layout (unit: mm)

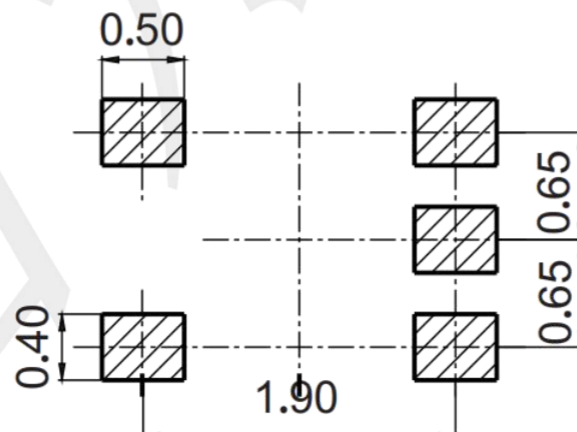


Package information (Unit: mm)

SOT353

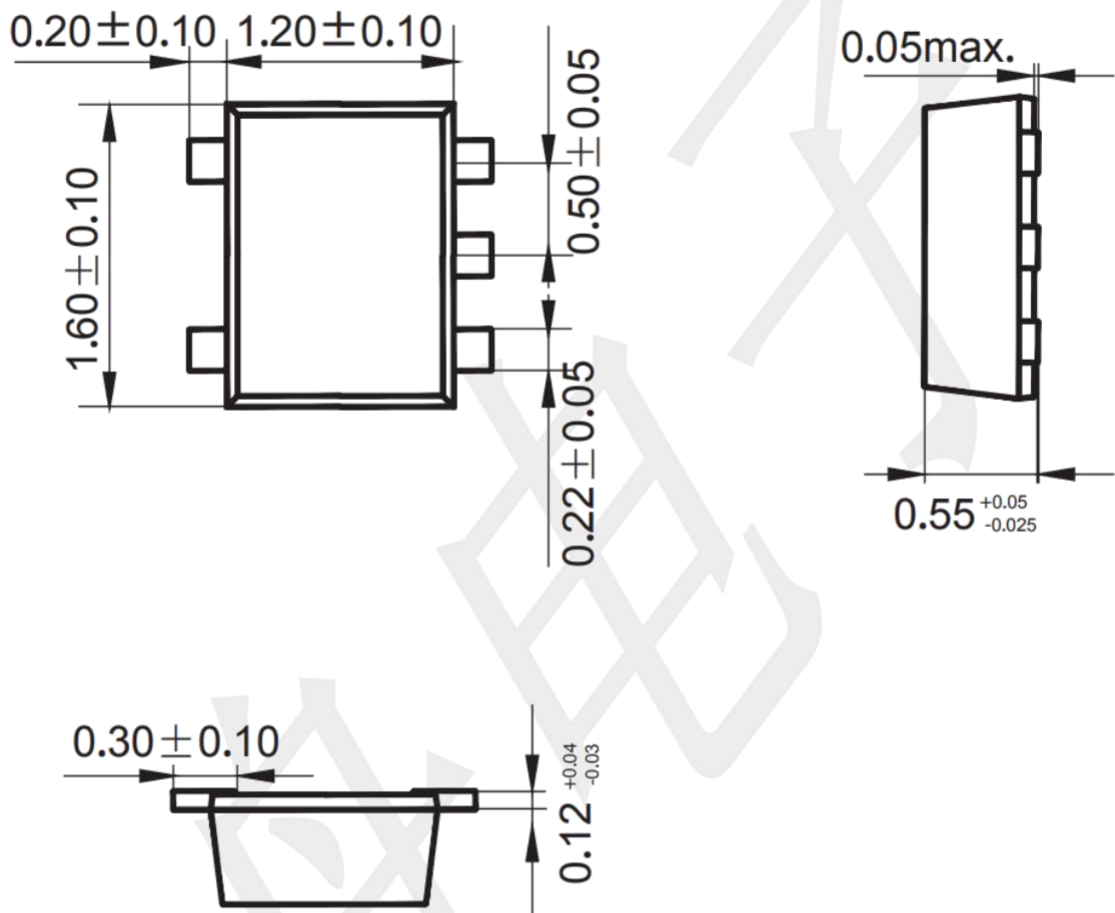


Mounting Pad Layout (unit: mm)

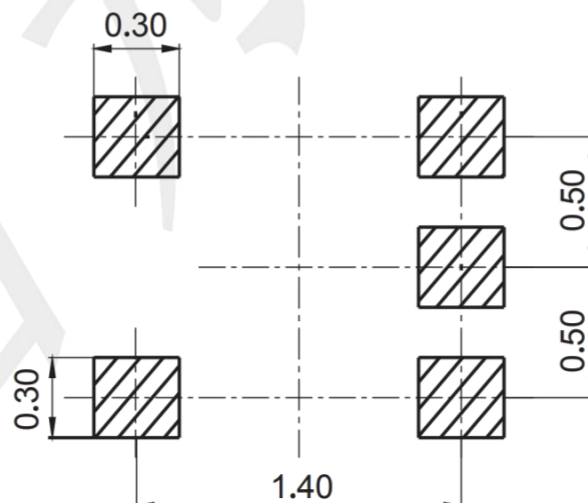


Package information (unit: mm)

SOT553

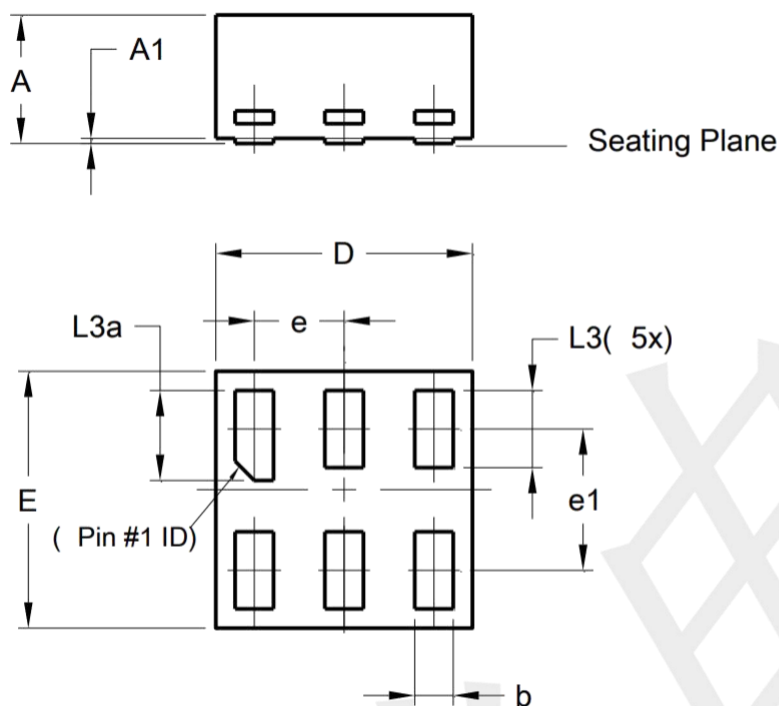


Mounting Pad Layout (unit: mm)



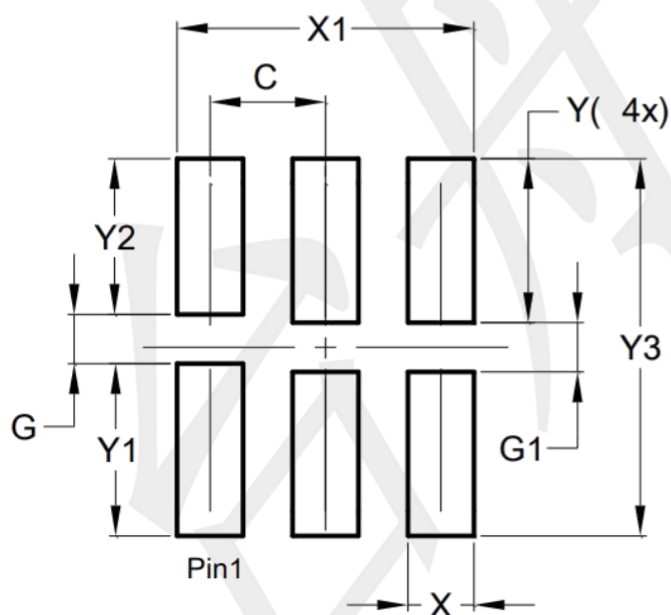
Package information (unit: mm)

DFN1X1-6



DFN1010-6 (Type B)			
Dim	Min	Max	Typ
A	-	0.50	0.39
A1	-	0.04	-
b	0.12	0.20	0.15
D	0.95	1.050	1.00
E	0.95	1.050	1.00
e	0.35 BSC		
e1	0.55 BSC		
L3	0.27	0.30	0.30
L3a	0.32	0.40	0.35
All Dimensions in mm			

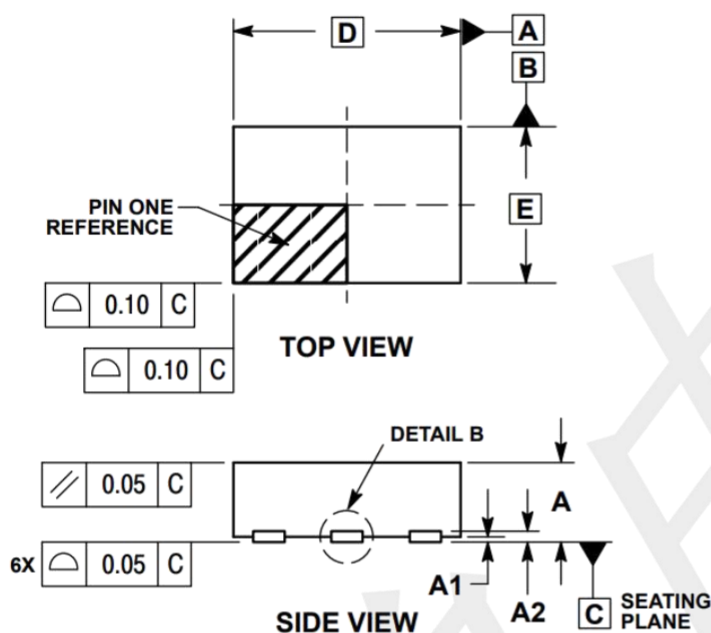
Mounting Pad Layout (unit: mm)



Dimensions	Value (in mm)
C	0.350
G	0.150
G1	0.150
X	0.200
X1	0.900
Y	0.500
Y1	0.525
Y2	0.475
Y3	1.150

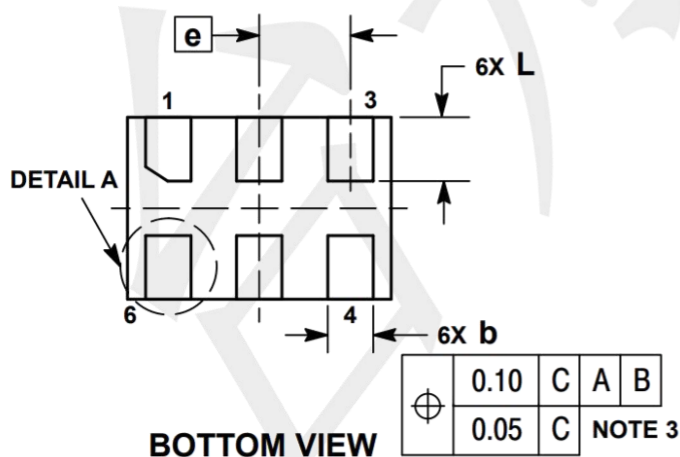
Package information (unit: mm)

DFN1510-6



DIM	MILLIMETERS	
	MIN	MAX
A	0.45	0.55
A1	0.00	0.05
A2	0.07 REF	
b	0.20	0.30
D	1.45 BSC	
E	1.00 BSC	
e	0.50 BSC	
L	0.30	0.40
L1	---	0.15

Mounting Pad Layout (unit: mm)



MOUNTING FOOTPRINT

